

# Synchronous Regulator with Bypass Mode, TINYBOOST<sup>®</sup>, 2.5 MHz, 1500 mA

## FAN48630

### Description

The FAN48630 allows systems to take advantage of new battery chemistries that can supply significant energy when the battery voltage is lower than the required voltage for system power ICs. By combining built-in power transistors, synchronous rectification, and low supply current; this IC provides a compact solution for systems using advanced Li-Ion battery chemistries.

The FAN48630 is a boost regulator designed to provide a minimum output voltage from a single-cell Li-Ion battery, even when the battery voltage is below system minimum. Output voltage regulation is guaranteed to a maximum load current of 1500 mA. Quiescent current in Shutdown Mode is less than 3  $\mu$ A, which maximizes battery life. The regulator transitions smoothly between Bypass and normal Boost Mode. The device can be forced into Bypass Mode to reduce quiescent current.

The FAN48630 is available in a 16-bump, 0.4 mm pitch, Wafer-Level Chip-Scale Package (WLCSP).

### Features

- Few External Components: 0.47  $\mu$ H Inductor and 0603 Case Size Input and Output Capacitors
- Input Voltage Range: 2.35 V to 5.5 V
- Fixed Output Voltage Options: 3.0 V to 5.0 V
- Maximum Continuous Load Current: 1500 mA at  $V_{IN}$  of 2.6 V Boosting  $V_{OUT}$  to 3.5 V
- Up to 96% Efficient
- True Bypass Operation when  $V_{IN} > V_{OUT\_TARGET}$
- Internal Synchronous Rectifier
- Soft-Start with True Load Disconnect
- Forced Bypass Mode
- $V_{SEL}$  Control to Optimize Target  $V_{OUT}$
- Short-Circuit Protection
- Low Operating Quiescent Current
- 16-Bump, 0.4 mm Pitch WLCSP
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### Applications

- Boost for Low-Voltage Li-ion Batteries, Brownout Prevention, Boosted Audio, USB OTG, and LTE / 3G RF Power
- Cell Phones, Smart Phones, Portable Instruments



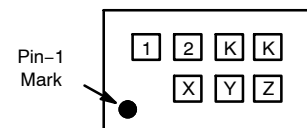
ON Semiconductor<sup>®</sup>

[www.onsemi.com](http://www.onsemi.com)



WLCSP16 1.78x1.78x0.586  
CASE 567SY

### MARKING DIAGRAM



- 12 = Alphanumeric Device Marking
- KK = Lot Rune Code
- X = Alphabetical Year Code
- Y = 2-weeks Date Code
- Z = Assembly Plant Code

### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

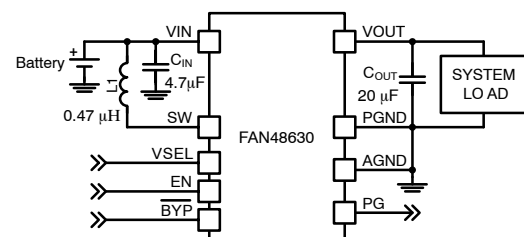


Figure 1. Typical Application

# FAN48630

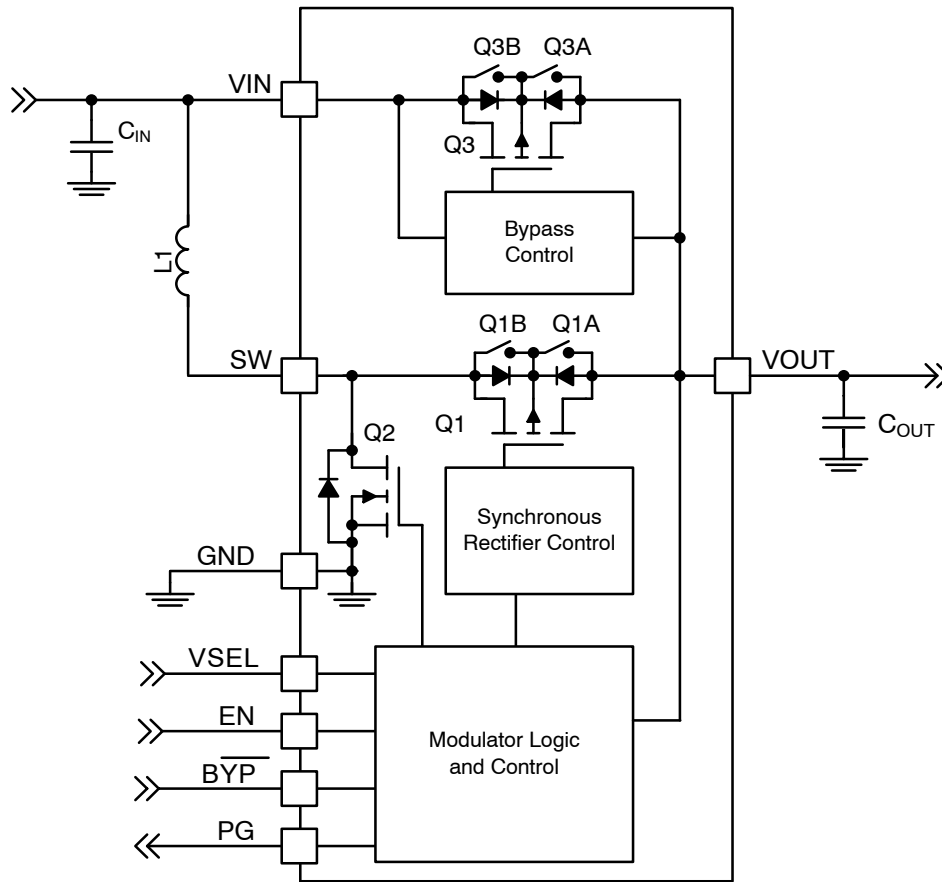
**Table 1. ORDERING INFORMATION**

Part Number	Output Voltage (Note 1) $V_{SELO}/V_{SEL1}$	Soft - Start	Forced Bypass	Operating Temperature	Package	Shipping†	Top Marking
FAN48630UC315X	3.15 / 3.33	FAST	Low $I_Q$	-40 to 85°C	16-Ball, 4x4 Array, 0.4mm Pitch, 250um Ball, Wafer-Level Chip-Scale Package (WLCSP)	Tape & Reel	J5
FAN48630BUC315X (Note 2)	3.15 / 3.33	FAST	Low $I_Q$				J5
FAN48630UC33X	3.30 / 3.49	FAST	Low $I_Q$				JX
FAN48630BUC33X (Note 2)	3.30 / 3.49	FAST	Low $I_Q$				JX
FAN48630BUC34X (Note 2)	3.20 / 3.40	FAST	Low $I_Q$				JR
FAN48630UC35X	3.50 / 3.70	FAST	Low $I_Q$				J6
FAN48630UC37AX	3.70 / 3.77	FAST	Low $I_Q$				JT
FAN48630UC45X	4.50 / 4.76	SLOW	OCP On				J7
FAN48630UC50X	5.00 / 5.29	SLOW	OCP On				J8

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

1. Other output voltages are available on request. Please contact a ON Semiconductor representative.
2. The FAN48630BUC315X, FAN48630BUC33X and FAN48630BUC34X include backside lamination.

## TYPICAL APPLICATION



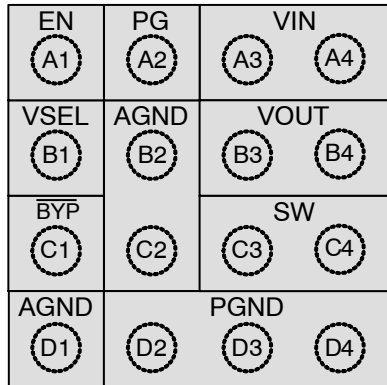
**Figure 2. Block Diagram**

# FAN48630

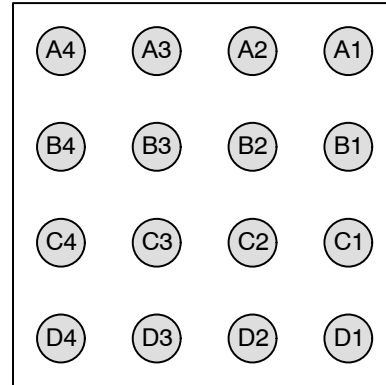
**Table 2. RECOMMENDED COMPONENTS**

Component	Description	Vendor	Parameter	Typ.	Unit
L <sub>1</sub>	0.47 $\mu$ H, 30%	Toko: DFE201612C DFR201612C Cyntec: PIFE20161B	L	0.47	$\mu$ H
			DCR (Series R)	40	m $\Omega$
C <sub>IN</sub>	4.7 $\mu$ F, 10%, 6.3 V, X5R, 0603	Murata: GRM188R60J475K TDK: C1608X5R0J475K	C	4.7	$\mu$ F
C <sub>OUT</sub>	2 x 10 $\mu$ F, 20%, 10 V, X5R, 0603	TDK: C1608X5R1A106M	C	20	$\mu$ F

## PIN CONFIGURATION



**Figure 3. Top Through View (Bumps Down)**



**Figure 4. Bottom View**

**Table 3. PIN DEFINITIONS**

Pin #	Name	Description
A1	EN	<u>Enable</u> . When this pin is HIGH, the circuit is enabled (Note 3).
A2	PG	<u>Power Good</u> . This is an open-drain output. PG is actively pulled LOW if output falls out of regulation due to overload or if thermal protection threshold is exceeded.
A3–A4	VIN	<u>Input Voltage</u> . Connect to Li-Ion battery input power source (Note 3).
B1	VSEL	<u>Output Voltage Select</u> . When boost is running, this pin can be used to select output voltage.
B2, C2, D1	AGND	<u>Analog Ground</u> . This is the signal ground reference for the IC. All voltage levels are measured with respect to this pin.
B3–B4	VOUT	<u>Output Voltage</u> . Place C <sub>OUT</sub> as close as possible to the device.
C1	$\overline{\text{BYP}}$	<u>Bypass</u> . This pin can be used to activate Forced Bypass Mode. When this pin is LOW, the bypass switches (Q3 and Q1) are turned on and the IC is otherwise inactive.
C3–C4	SW	<u>Switching Node</u> . Connect to inductor.
D2–D4	PGND	<u>Power Ground</u> . This is the power return for the IC. The C <sub>OUT</sub> bypass capacitor should be returned with the shortest path possible to these pins.

3. Do not connect the EN pin to VIN. A logic voltage of 1.8 V should control the EN pin and enable/disable the device.

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**Table 4. ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Min.	Max.	Unit
V <sub>IN</sub>	V <sub>IN</sub> Input Voltage	-0.3	6.5	V
V <sub>OUT</sub>	V <sub>OUT</sub> Output Voltage		6.0	V
	SW Node	DC	8.0	V
		Transient: 10 ns, 3 MHz	8.0	V
	Other Pins	-0.3	6.5 (Note 4)	V
ESD	Electrostatic Discharge Protection Level	Human Body Model per JESD22-A114	3.0	kV
		Charged Device Model per JESD22-C101	1.5	kV
T <sub>J</sub>	Junction Temperature	-40	+150	°C
T <sub>STG</sub>	Storage Temperature	-65	+150	°C
T <sub>L</sub>	Lead Soldering Temperature, 10 Seconds		+260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

4. Lesser of 6.5 V or V<sub>IN</sub> + 0.3 V.

**Table 5. RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min.	Max.	Unit
V <sub>IN</sub>	Supply Voltage	2.35	5.5	V
I <sub>OUT</sub>	Output Current	0	1500	mA
T <sub>A</sub>	Ambient Temperature	-40	+85	°C
T <sub>J</sub>	Junction Temperature	-40	+125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

**Table 6. THERMAL CHARACTERISTICS**

Symbol	Parameter	Typ.	Unit
θ <sub>JA</sub>	Junction-to-Ambient Thermal Resistance	80	°C/W
θ <sub>JB</sub>	Junction-to-Board Thermal Resistance	42	

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer Fairchild® evaluation boards (1 oz copper on all layers). Special attention must be paid not to exceed junction temperature T<sub>J(max)</sub> at a given ambient temperature T<sub>A</sub>.

**Table 7. ELECTRICAL CHARACTERISTICS**

Recommended operating conditions, unless otherwise noted, circuit per Figure 1, V<sub>IN</sub> = 2.35 V to V<sub>OUT</sub>, T<sub>A</sub> = -40°C to 85°C. Typical values are given V<sub>IN</sub> = 3.0 V and T<sub>A</sub> = 25°C.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
I <sub>Q</sub>	V <sub>IN</sub> Quiescent Current	Bypass Mode V <sub>OUT</sub> = 3.5 V, V <sub>IN</sub> = 4.2 V		140	190	μA
		Boost Mode V <sub>OUT</sub> = 3.5 V, V <sub>IN</sub> = 2.5 V		150	250	μA
		Shutdown: EN = 0, V <sub>IN</sub> = 3.0 V		1.5	5.0	μA
		Forced Bypass Mode V <sub>OUT</sub> = 3.5 V V <sub>IN</sub> = 3.5 V	Low I <sub>Q</sub> OCP On		4 45	10 90
I <sub>LK</sub>	V <sub>OUT</sub> to V <sub>IN</sub> Reverse Leakage	V <sub>OUT</sub> = 5 V, EN = 0		0.2	1.0	μA
I <sub>LK_OUT</sub>	V <sub>OUT</sub> Leakage Current	V <sub>OUT</sub> = 0, EN = 0, V <sub>IN</sub> = 4.2 V		0.1	1.0	μA
V <sub>UVLO</sub>	Under-Voltage Lockout	V <sub>IN</sub> Rising		2.20	2.35	V
V <sub>UVLO_HYS</sub>	Under-Voltage Lockout Hysteresis			200		mV
V <sub>PG(OL)</sub>	PG Low	I <sub>PG</sub> = 5 mA			0.4	V
I <sub>PG_LK</sub>	PG Leakage Current	V <sub>PG</sub> = 5 V			1	μA
V <sub>IH</sub>	Logic Level High EN, VSEL, BYP		1.2			V
V <sub>IL</sub>	Logic Level Low EN, VSEL, BYP				0.4	V

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**Table 7. ELECTRICAL CHARACTERISTICS** (continued)

Recommended operating conditions, unless otherwise noted, circuit per Figure 1,  $V_{IN} = 2.35\text{ V}$  to  $V_{OUT}$ ,  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$ . Typical values are given  $V_{IN} = 3.0\text{ V}$  and  $T_A = 25^\circ\text{C}$ .

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
$R_{LOW}$	Logic Control Pin Pull Downs (LOW Active)	BYP, VSEL, EN		300		$k\Omega$
$I_{PD}$	Weak Current Source Pull-Down	BYP, VSEL, EN		100		nA
$V_{REG}$	Output Voltage Accuracy	Referred to GND, DC, $V_{OUT} - V_{IN} > 100\text{ mV}$	-2		4	%
$V_{TRSP}$	Load Transient Response	500–1250 mA, $V_{IN} = 3.6\text{ V}$ , $V_{OUT} = 5.0\text{ V}$		$\pm 4$		%
$t_{ON}$	On-Time	$V_{IN} = 3.0\text{ V}$ , $V_{OUT} = 3.5\text{ V}$ , Load $> 1000\text{ mA}$		80		ns
$f_{SW}$	Switching Frequency	$V_{IN} = 3.6\text{ V}$ , $V_{OUT} = 5.0\text{ V}$ , Load = 1000 mA	2.0	2.5	3.0	MHz
$I_{V\_LIM}$	Boost Valley Current Limit	$V_{IN} = 2.6\text{ V}$	2.6	2.9	3.1	A
$I_{V\_LIM\_SS}$	Boost Valley Current Limit During SS	$V_{IN} = 2.6\text{ V}$		1.6		A
$V_{MIN\_1.5A}$	Minimum $V_{IN}$ for 1500 mA Load (Short Term)	$V_{OUT} = 5.0\text{ V}$ , $T_J < 120^\circ\text{C}$		3.0		V
		$V_{OUT} = 4.5\text{ V}$ , $T_J < 120^\circ\text{C}$		2.8		V
		$V_{OUT} = 3.5\text{ V}$ , $T_J < 120^\circ\text{C}$		2.35		V
		$V_{OUT} = 3.15\text{ V}$ , $T_J < 120^\circ\text{C}$		2.35		V
$I_{SS\_PK}$	Soft-Start Input Peak Current Limit	LIN1	Slow		350	mA
			Fast		800	mA
		LIN2	Slow		700	mA
			Fast		1600	mA
$t_{SS}$	Soft-Start EN HIGH to Regulation	Slow, 50 $\Omega$ Load		1300		$\mu\text{s}$
		Fast, 50 $\Omega$ Load		600		$\mu\text{s}$
$V_{OCP}$	OCP Comparator Threshold	$V_{IN} = 5.0\text{ V}$ , $V_{IN} - V_{OUT}$		200		mV
$V_{OVP}$	Output Over-Voltage Protection Threshold			6.0	6.3	V
$V_{OVP\_HYS}$	Output Over-Voltage Protection Hysteresis			300		mV
$R_{DS(ON)N}$	N-Channel Boost Switch $R_{DS(ON)}$	$V_{IN} = 3.5\text{ V}$ , $V_{OUT} = 3.5\text{ V}$		85	120	$m\Omega$
$R_{DS(ON)P}$	P-Channel Sync Rectifier $R_{DS(ON)}$	$V_{IN} = 3.5\text{ V}$ , $V_{OUT} = 3.5\text{ V}$		65	85	$m\Omega$
$R_{DS(ON)P\_BYP}$	P-Channel Bypass Switch $R_{DS(ON)}$	$V_{IN} = 3.5\text{ V}$ , $V_{OUT} = 3.5\text{ V}$		65	85	$m\Omega$
$T_{120A}$	T120 Activation Threshold			120		$^\circ\text{C}$
$T_{120R}$	T120 Release Threshold			100		$^\circ\text{C}$
$T_{150T}$	T150 Threshold			150		$^\circ\text{C}$
$T_{150H}$	T150 Hysteresis			20		$^\circ\text{C}$
$t_{RST}$	FAULT Restart Timer			20		ms

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

Unless otherwise specified;  $V_{IN} = 3.6\text{ V}$ ,  $V_{OUT} = 5\text{ V}$ , and  $T_A = 25^\circ\text{C}$ ; circuit and components according to Figure 1.

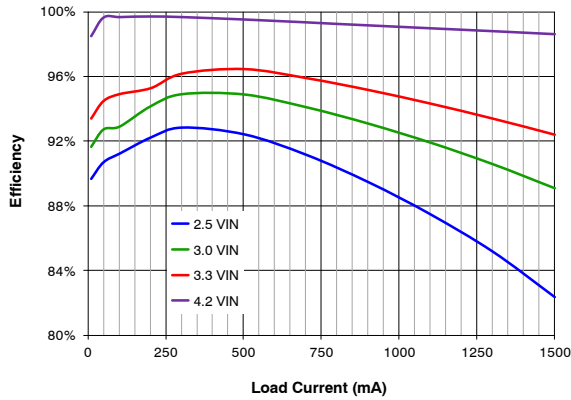


Figure 5. Efficiency vs. Load Current and Input Voltage,  $V_{OUT} = 3.5\text{ V}$

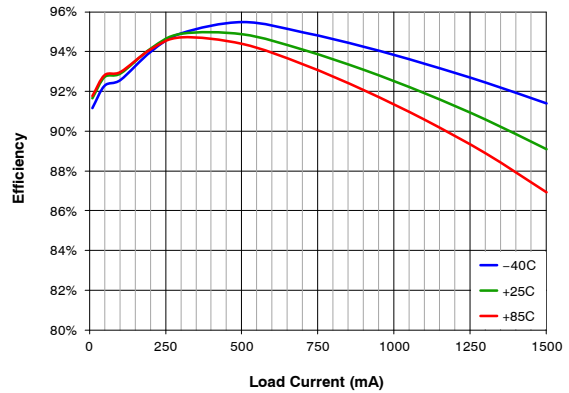


Figure 6. Efficiency vs. Load Current and Temperature,  $V_{IN} = 3.0\text{ V}$ ,  $V_{OUT} = 3.5\text{ V}$

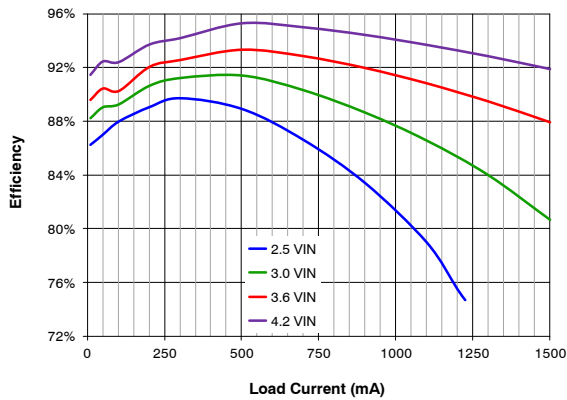


Figure 7. Efficiency vs. Load Current and Input Voltage

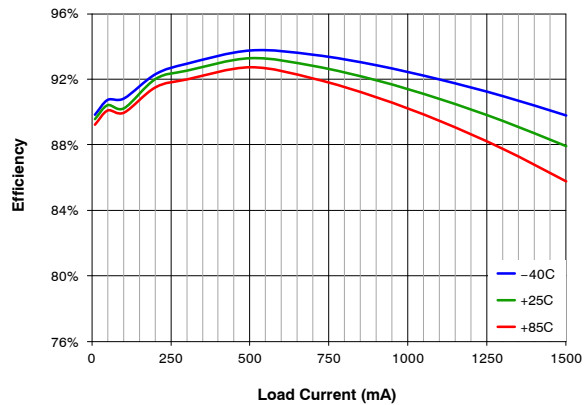


Figure 8. Efficiency vs. Load Current and Temperature

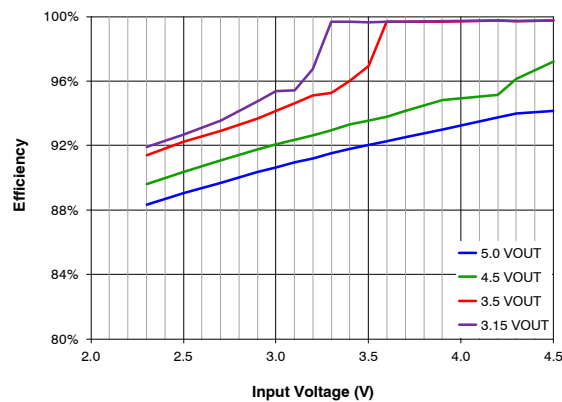


Figure 9. Efficiency vs. Input Voltage and Output Voltage, 200 mA Load

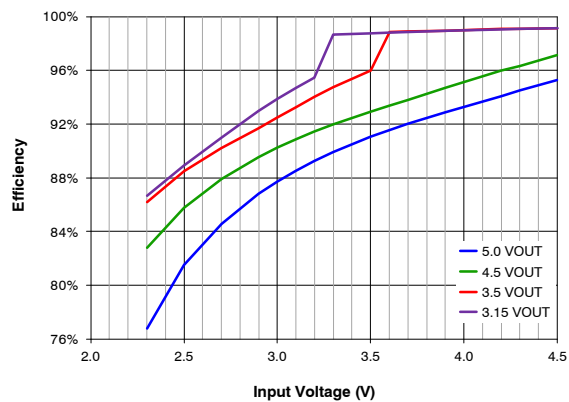


Figure 10. Efficiency vs. Input Voltage and Output Voltage, 1000 mA Load

TYPICAL CHARACTERISTICS (CONTINUED)

Unless otherwise specified;  $V_{IN} = 3.6\text{ V}$ ,  $V_{OUT} = 5\text{ V}$ , and  $T_A = 25^\circ\text{C}$ ; circuit and components according to Figure 1.

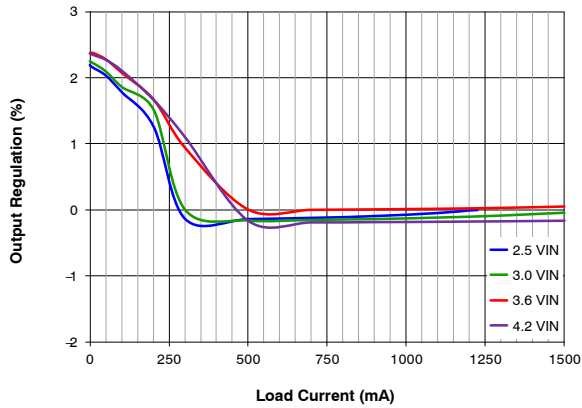


Figure 11. Output Regulation vs. Load Current and Input Voltage (Normalized to  $3.6\text{ V}_{IN}$ ,  $500\text{ mA}$  Load)

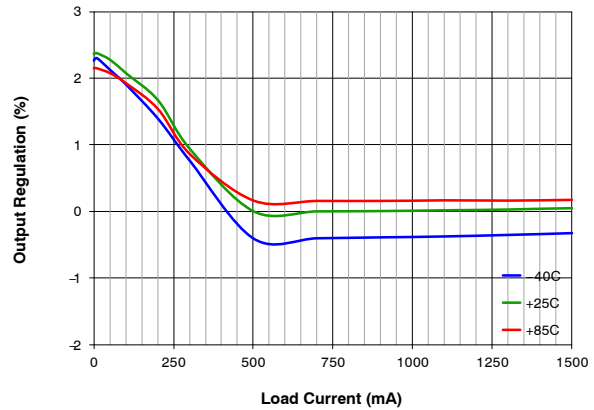


Figure 12. Output Regulation vs. Load Current and Temperature (Normalized to  $3.6\text{ V}_{IN}$ ,  $500\text{ mA}$  Load,  $T_A = 25^\circ\text{C}$ )

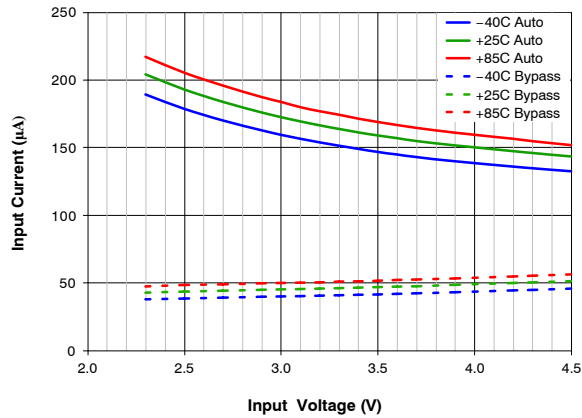


Figure 13. Quiescent Current vs. Input Voltage, Temperature and Mode,  $V_{OUT} = 5.0\text{ V}$ , Forced Bypass, OCP Active

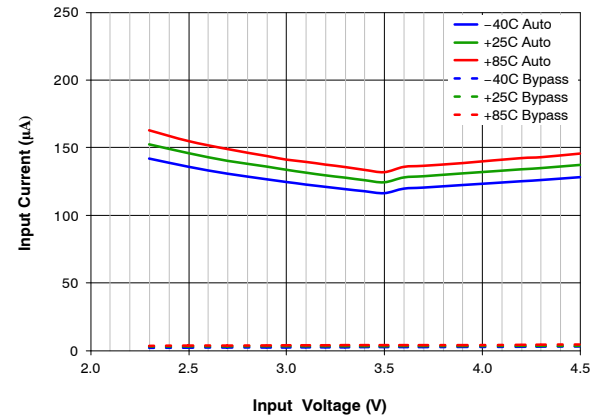


Figure 14. Quiescent Current vs. Input Voltage, Temperature and Mode,  $V_{OUT} = 3.5\text{ V}$ , Forced Bypass, Low  $I_Q$

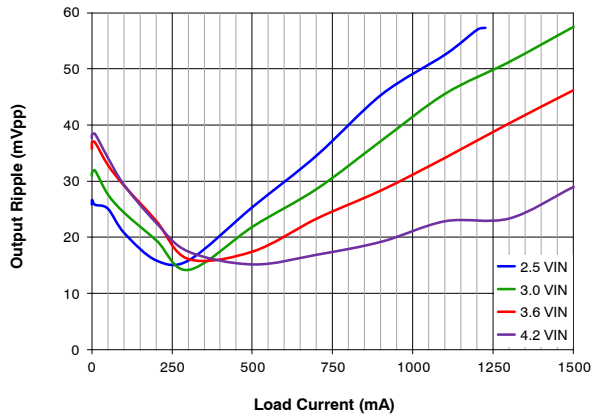


Figure 15. Output Ripple vs. Load Current and Input Voltage

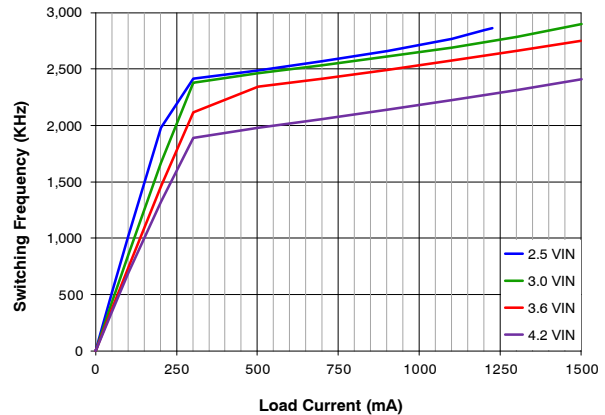


Figure 16. Frequency vs. Load Current and Input Voltage

TYPICAL CHARACTERISTICS (CONTINUED)

Unless otherwise specified;  $V_{IN} = 3.6\text{ V}$ ,  $V_{OUT} = 5\text{ V}$ , and  $T_A = 25^\circ\text{C}$ ; circuit and components according to Figure 1.

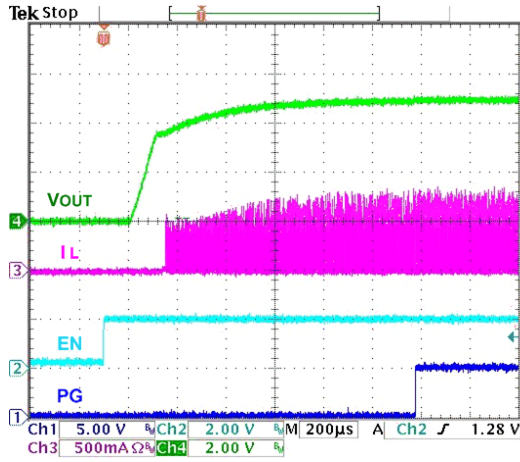


Figure 17. Startup, 50 Ω Load

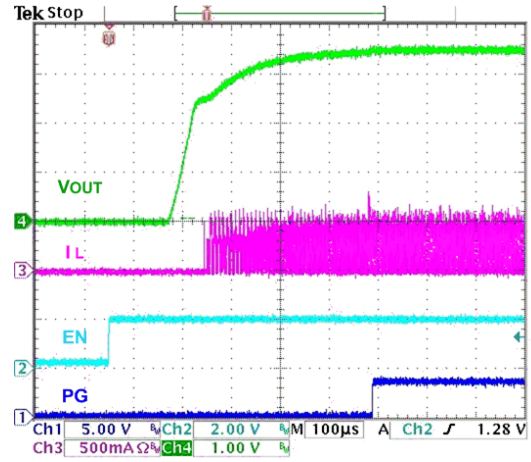


Figure 18. Startup, 50 Ω Load,  
 $V_{IN} = 2.5\text{ V}$ ,  $V_{OUT} = 3.5\text{ V}$

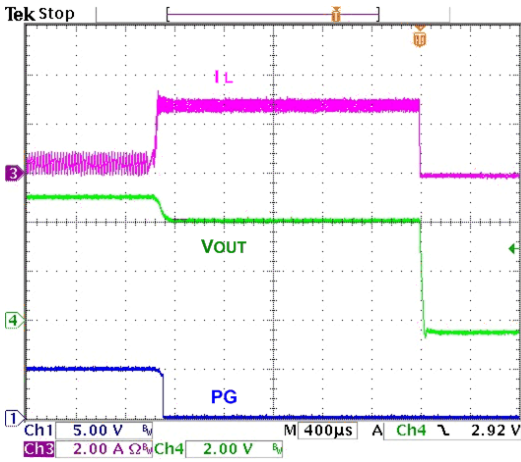


Figure 19. Overload Protection

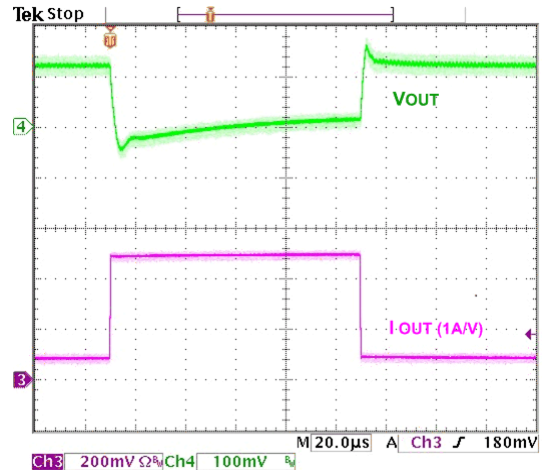


Figure 20. Load Transient, 100–500 mA,  
100 ns Edge

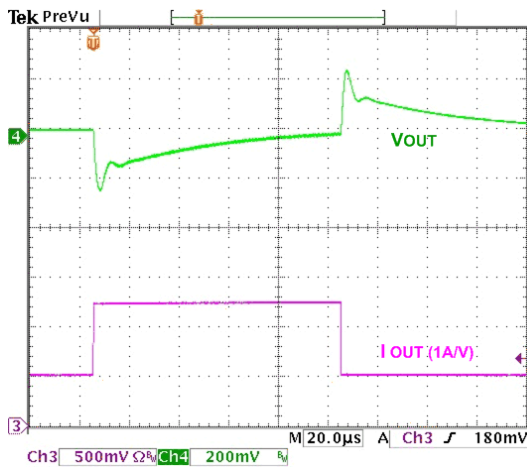


Figure 21. Load Transient, 500–1250 mA,  
100 ns Edge

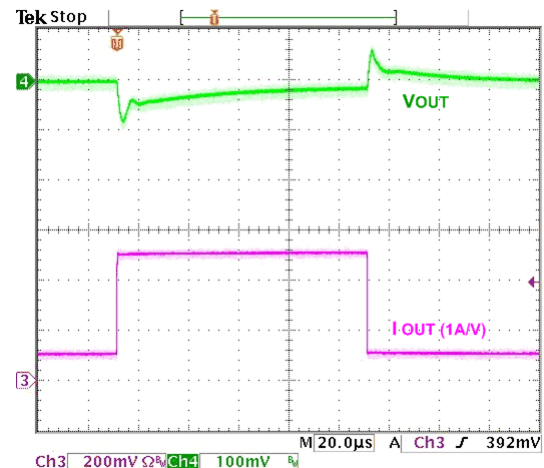


Figure 22. Load Transient, 100–500 mA,  
100 ns Edge,  $V_{IN} = 3\text{ V}$ ,  $V_{OUT} = 3.5\text{ V}$



TYPICAL CHARACTERISTICS (CONTINUED)

Unless otherwise specified;  $V_{IN} = 3.6\text{ V}$ ,  $V_{OUT} = 5\text{ V}$ , and  $T_A = 25^\circ\text{C}$ ; circuit and components according to Figure 1.

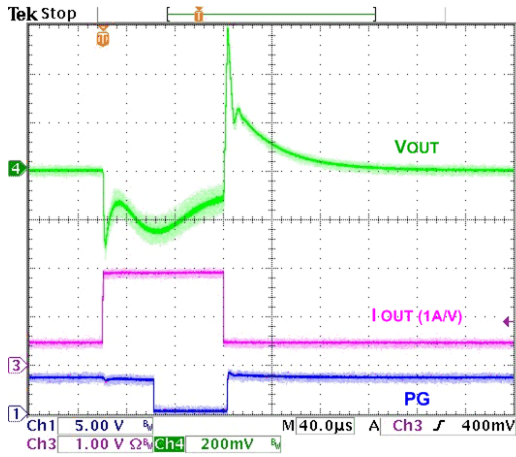


Figure 23. Transient Overload, 500–1950 mA, 100 ns Edge,  $V_{IN} = 3\text{ V}$ ,  $V_{OUT} = 3.5\text{ V}$

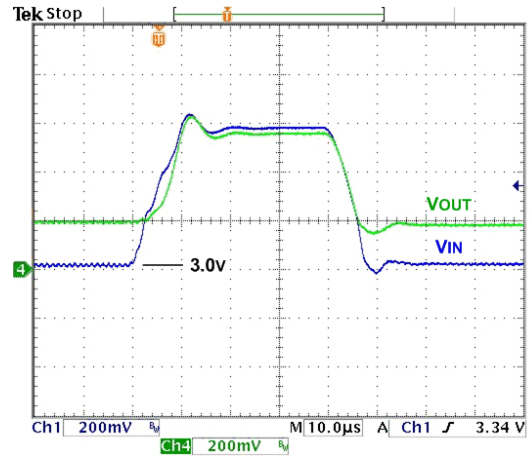


Figure 24. Line Transient, 3.0–3.6  $V_{IN}$ , 10  $\mu\text{s}$  Edge, 500 mA Load,  $V_{OUT} = 3.15\text{ V}$

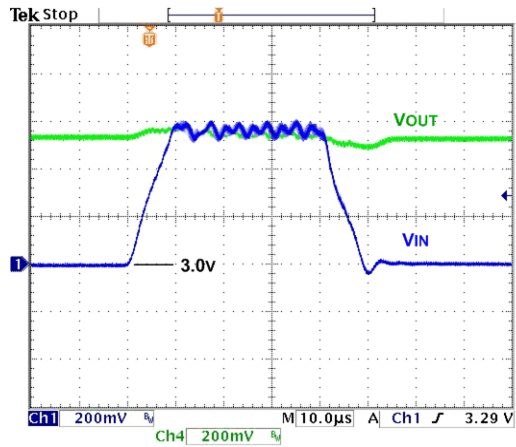


Figure 25. Line Transient, 3.0–3.6  $V_{IN}$ , 10  $\mu\text{s}$  Edge, 1,000 mA Load,  $V_{OUT} = 3.5\text{ V}$

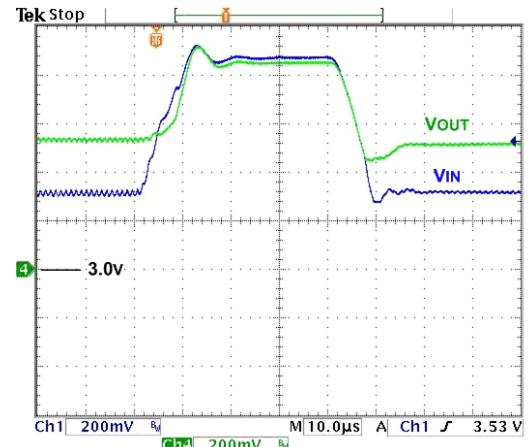


Figure 26. Line Transient, 3.3–3.9  $V_{IN}$ , 10  $\mu\text{s}$  Edge, 500 mA load,  $V_{OUT} = 3.5\text{ V}$

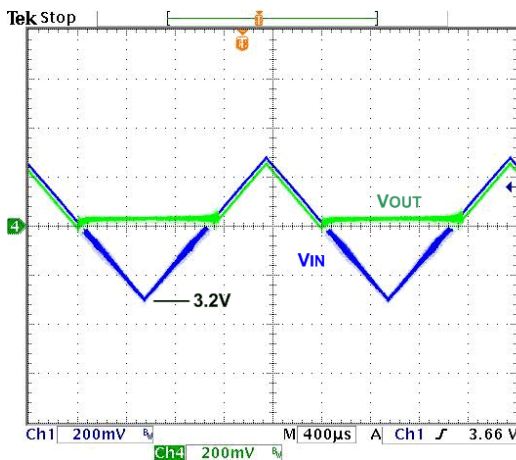


Figure 27. Bypass Entry / Exit, Slow  $V_{IN}$  Ramp 1 ms Edge, 500 mA Load,  $V_{OUT} = 3.5\text{ V}$ , 3.2 – 3.8  $V_{IN}$

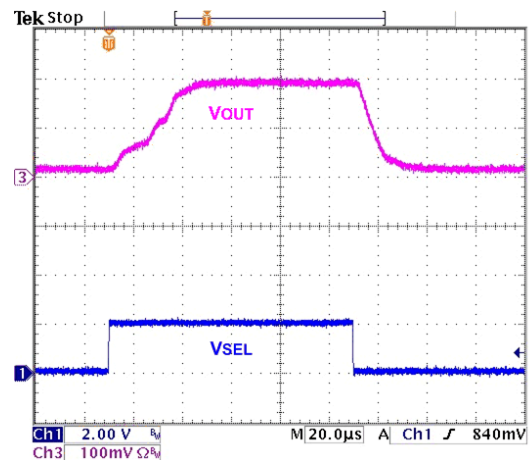


Figure 28.  $V_{SEL}$  Step,  $V_{IN} = 3\text{ V}$ ,  $V_{OUT} = 3.5\text{ V}$ , 500 mA Load

CIRCUIT DESCRIPTION

FAN48630 is a synchronous boost regulator, typically operating at 2.5 MHz in Continuous Conduction Mode (CCM), which occurs at moderate to heavy load current and low  $V_{IN}$  voltages. The regulator includes a Bypass Mode that activates when  $V_{IN}$  is above the boost regulator’s setpoint.

In anticipation of a heavy load transition, the setpoint can be adjusted upward by fixed amounts with the VSEL pin to reduce the required system headroom during lighter-load operation to save power.

Table 8. OPERATING STATES

Mode	Description	Invoked When
LIN	Linear Startup	$V_{IN} > V_{OUT}$
SS	Boost Soft-Start	$V_{OUT} < V_{OUT\_TARGET}$
BST	Boost Operating Mode	$V_{OUT} = V_{OUT\_TARGET}$
BPS	Bypass Mode	$V_{IN} > V_{OUT\_TARGET}$

Boost Mode

The FAN48630 uses a current-mode modulator to achieve excellent transient response and smooth transitions between CCM and Discontinuous Conduction Mode (DCM) operation. During CCM operation, the device maintains a switching frequency of about 2.5 MHz. In light-load operation (DCM), frequency is reduced to maintain high efficiency.

Table 9. BOOST STARTUP SEQUENCE

Start State	Entry	Exit	End State	Timeout (µs)
LIN1	$V_{IN} > UVLO$ , EN = 1	$V_{OUT} > V_{IN}-300\text{ mV}$	SS	
			LIN2	512
LIN2	LIN1 Exit	$V_{OUT} > V_{IN}-300\text{ mV}$	SS	
		TIMEOUT	FAULT	1024
SS	LIN1 or LIN2 Exit	$V_{OUT} = V_{OUT\_TARGET}$	BST	
		OVERLOAD TIMEOUT	FAULT	64

Shutdown and Startup

If EN is LOW, all bias circuits are off and the regulator is in Shutdown Mode. During shutdown, current flow is prevented from  $V_{IN}$  to  $V_{OUT}$ , as well as reverse flow from  $V_{OUT}$  to  $V_{IN}$ . During startup, it is recommended to keep DC current draw below 500 mA.

LIN State

When EN is HIGH and  $V_{IN} > UVLO$ , the regulator attempts to bring  $V_{OUT}$  within 300 mV of  $V_{IN}$  using the

internal fixed current source from  $V_{IN}$  (Q3). The current is limited to LIN1 set point.

If  $V_{OUT}$  reaches  $V_{IN}-300\text{ mV}$  during LIN1 Mode, the SS state is initiated. Otherwise, LIN1 times out after 512 µs and LIN2 Mode is entered.

In LIN2 Mode, the current source is incremented to 2 A. If  $V_{OUT}$  fails to reach  $V_{IN}-300\text{ mV}$  after 1024 µs, a fault condition is declared.

SS State

Upon the successful completion of the LIN state ( $V_{OUT} \geq V_{IN}-300\text{ mV}$ ), the regulator begins switching with boost pulses current limited to 50% of nominal level.

During SS state,  $V_{OUT}$  is ramped up by stepping the internal reference. If  $V_{OUT}$  fails to reach regulation during the SS ramp sequence for more than 64 µs, a fault condition is declared. If large  $C_{OUT}$  is used, the reference is automatically stepped slower to avoid excessive input current draw.

BST State

This is a normal operating state of the regulator.

BPS State

If  $V_{IN}$  is above  $V_{REG}$  when the SS Mode successfully completes, the device transitions directly to BPS Mode.

FAST and SLOW Soft-Start Options

The fast startup versions feature EN to regulation time of 600 µs. LIN1 and LIN2 phase currents are doubled compared to SLOW options, SS phase is also faster.

Slow startup achieves EN to regulation time of 1300 µs to reduce inrush current.

Table 10. OPERATING STATES

EN	BYP	Mode	$V_{OUT}$
0	0	Shutdown	0
	1	Shutdown	0
1	0	Forced Bypass	$V_{IN}$
	1	Auto Bypass	$V_{OUT\_TARGET}$ or $V_{IN}$ (or $V_{IN} > V_{OUT\_TARGET}$ )

FAULT State

The regulator enters the FAULT state under any of the following conditions:

- $V_{OUT}$  fails to achieve the voltage required to advance from LIN state to SS state.
- $V_{OUT}$  fails to achieve the voltage required to advance from SS state to BST state.
- Boost current limit triggers for 2 ms during the BST state.
- $V_{DS}$  protection threshold is exceeded during BPS state.

Once a fault is triggered, the regulator stops switching and presents a high-impedance path between  $V_{IN}$  and  $V_{OUT}$ . After waiting 20 ms, a restart is attempted.

**Power Good**

Power good is 0 FAULT, 1 POWER GOOD, open-drain output.

The Power good pin is provided for signaling the system when the regulator has successfully completed soft-start and no faults have occurred. Power good also functions as an early warning flag for high die temperature and overload conditions.

**Over-Temperature**

The regulator shuts down when the die temperature exceeds 150°C. Restart occurs when the IC has cooled by approximately 20°C.

**Bypass Operation**

In normal operation, the device automatically transitions from Boost Mode to Bypass Mode, if  $V_{IN}$  goes above target  $V_{OUT}$ . In Bypass Mode, the device fully enhances both Q1 and Q3 to provide a very low impedance path from  $V_{IN}$  to  $V_{OUT}$ . Entry to the Bypass Mode is triggered by condition where  $V_{IN} > V_{OUT}$  and no switching has occurred during past 5  $\mu$ s. To soften the entry to Bypass Mode, Q3 is driven as a linear current source for the first 5  $\mu$ s. Bypass Mode exit is triggered when  $V_{OUT}$  reaches the target  $V_{OUT}$  voltage. During Automatic Bypass Mode, the device is short-circuit protected by voltage comparator tracking the voltage drop from  $V_{IN}$  to  $V_{OUT}$ ; if the drop exceeds 200 mV, FAULT is declared.

With sufficient load to enforce CCM operation, the Bypass Mode to Boost Mode transition occurs at the target  $V_{OUT}$ . The corresponding input voltage at the transition point is:

$$V_{IN} \leq V_{OUT} + I_{LOAD} * (DCR_L + R_{DS(ON)P}) \parallel R_{DS(ON)BYP} \quad (\text{eq. 1})$$

The Bypass Mode entry threshold has 25 mV hysteresis imposed at  $V_{OUT}$  to prevent cycling between modes. The transition from Boost Mode to Bypass Mode occurs at the target  $V_{OUT}+25$  mV. The corresponding input voltage is:

$$V_{IN} \geq V_{OUT} + 25\text{mV} + I_{LOAD} * (DCR_L + R_{DS(ON)P}) \quad (\text{eq. 2})$$

- PG is released HIGH when the soft-start sequence is successfully completed.
- PG is pulled LOW when PMOS current limit has triggered for 64  $\mu$ s OR the die the temperature exceeds 120°C. PG is re-asserted when the device cools below to 100°C.
- Any FAULT condition causes PG to be de-asserted.

**Forced Bypass**

Entry to Forced Bypass Mode initiates with a current limit on Q3 and then proceeds to a true bypass state. To prevent reverse current to the battery, the device waits until output discharges below  $V_{IN}$  before entering Forced Bypass Mode.

For Low-IQ Forced Bypass versions, after the transition is complete, most of the internal circuitry is disabled to minimize quiescent current draw. Short-circuit, UVLO, output OVP and over-temperature protections are inactive in Forced Bypass Mode.

For OCP-On Forced Bypass versions, during Forced Bypass Mode, the device is short-circuit protected by a voltage comparator tracking the voltage drop from  $V_{IN}$  to  $V_{OUT}$ . If the drop exceeds 200 mV, a FAULT is declared. The over-temperature protection is also active.

**VSEL**

$V_{SEL}$  can be asserted in anticipation of a positive load transient. Raising  $V_{SEL}$  increases  $V_{OUT\_TARGET}$  by a fixed amount and  $V_{OUT}$  is stepped to the corresponding target output voltage in 20  $\mu$ s. The functionality can also be utilized to mitigate undershoot during severe line transients, while minimizing  $V_{OUT}$  during more benign operating conditions to save power.

**EN**

Setting the EN pin voltage below 0.4 V disables the part. Placing the voltage above 1.2 V enables the part. Do not connect the EN pin to  $V_{IN}$ . A logic voltage of 1.8 V should control the EN pin and enable/disable the device. The EN pin should be pulled HIGH after the  $V_{IN}$  voltage has reached a minimum voltage of 2.3 V.

APPLICATION INFORMATION

Output Capacitance (C<sub>OUT</sub>)

Stability

The effective capacitance (C<sub>EFF</sub>) of small, high-value, ceramic capacitors decreases as bias voltage increases. FAN48630 is guaranteed for stable operation with the minimum value of C<sub>EFF</sub> (C<sub>EFF(MIN)</sub>) outlined in Table 11 below.

Table 11. MINIMUM C<sub>EFF</sub> REQUIRED FOR STABILITY

Operating Conditions		C <sub>EFF(MIN)</sub> (μF)
V <sub>OUT</sub> (V)	I <sub>LOAD</sub> (mA)	
3.15	0 to 1500	12
3.5	0 to 1500	9
4.5 and 5	0 to 1500	6

C<sub>EFF</sub> varies with manufacturer, material, and case size.

Inductor Selection

Recommended nominal inductance value is 0.47 μH.

FAN48630 employs valley-current limiting; peak inductor current can reach 3.8 A for a short duration during overload conditions. Saturation effects cause the inductor current ripple to become higher under high loading as only valley of the inductor current ripple is controlled.

For FAN48630UC315X, FAN48630BUC315X, FAN48630UC33X and FAN48630BUC33X, a 0.33 μH inductor can be used for improved transient performance.

Startup

Input current limiting is in effect during soft-start, which limits the current available to charge C<sub>OUT</sub> and any additional capacitance on the V<sub>OUT</sub> line. If the output fails to achieve regulation within the limits described in the Startup section, a FAULT occurs, causing the circuit to shut down then restart after a significant time period. If the total combined output capacitance is very high, the circuit may not start on the first attempt, but eventually achieves regulation if no load is present. If a high-current load and high capacitance are both present during soft-start, the circuit may fail to achieve regulation and continually attempts soft-start, only to have the output capacitance discharged by the load when in a FAULT state.

Output Voltage Ripple

Output voltage ripple is inversely proportional to C<sub>OUT</sub>. During t<sub>ON</sub>, when the boost switch is on, all load current is supplied by C<sub>OUT</sub>. Output ripple is calculated as:

$$V_{RIPPLE(P-P)} = t_{ON} * \frac{I_{LOAD}}{C_{OUT}} \quad (eq. 3)$$

and

$$t_{ON} = t_{SW} * D = t_{SW} * \left(1 - \frac{V_{IN}}{V_{OUT}}\right) \quad (eq. 4)$$

therefore:

$$V_{RIPPLE(P-P)} = t_{SW} * \left(1 - \frac{V_{IN}}{V_{OUT}}\right) * \frac{I_{LOAD}}{C_{OUT}} \quad (eq. 5)$$

and

$$t_{SW} = \frac{1}{f_{SW}} \quad (eq. 6)$$

As can be seen from eq. 5, the maximum V<sub>RIPPLE</sub> occurs when V<sub>IN</sub> is at minimum and I<sub>LOAD</sub> is at maximum.

Layout Recommendations

The layout recommendations below highlight various top-copper pours using different colors.

To minimize spikes at V<sub>OUT</sub>, C<sub>OUT</sub> must be placed as close as possible to PGND and V<sub>OUT</sub>, as shown in Figure 29.

For thermal reasons, it is suggested to maximize the pour area for all planes other than SW. Especially the ground pour should be set to fill all available PCB surface area and tied to internal layers with a cluster of thermal vias.

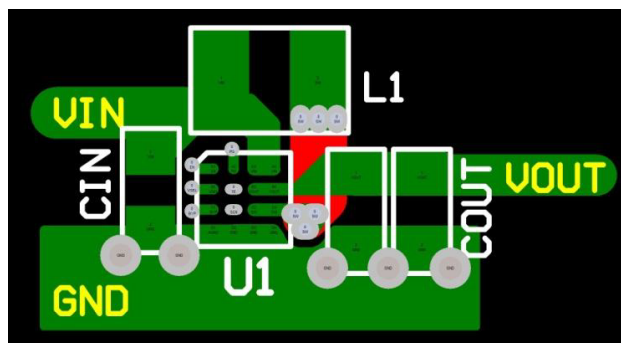


Figure 29. Layout Recommendation

Table 12. PRODUCT-SPECIFIC DIMENSIONS

D	E	X	Y
1.780 ±0.030	1.780 ±0.030	0.290	0.290

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# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

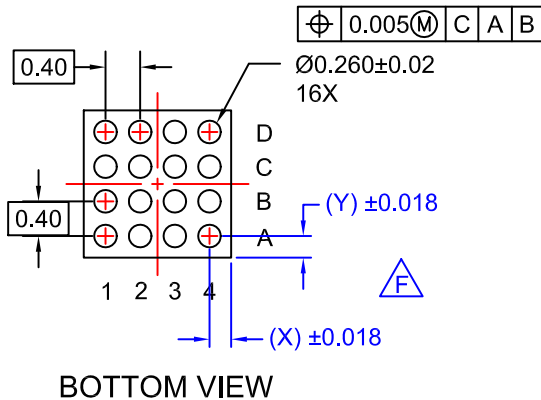
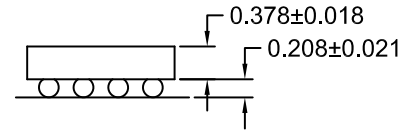
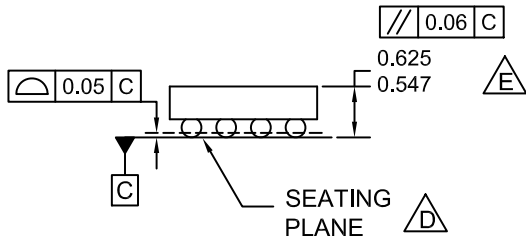
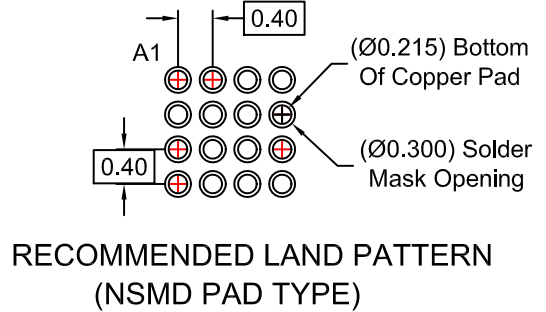
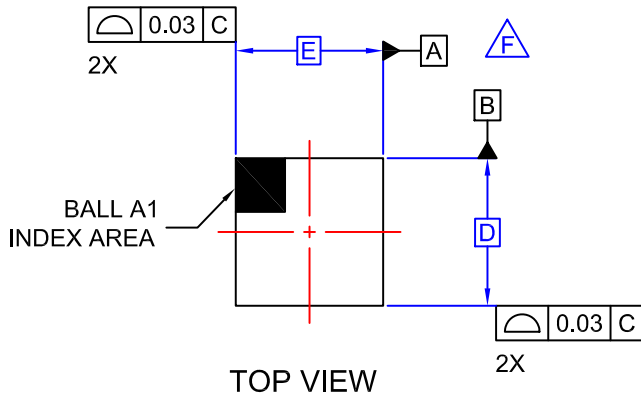
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### WLCSP16 1.78x1.78x0.586

CASE 567SY  
ISSUE O

DATE 30 NOV 2016



#### NOTES

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE NOMINAL HEIGHT IS  $586 \pm 39$  MICRONS (547-625 MICRONS).
- F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

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